

Addendum

Addendum to “Large negative Goos–Hanchen shift at metal surfaces”, [Opt. Comm. 276 (2007) 206]

P.T. Leung^{a,*}, C.W. Chen^{b,c}, H.-P. Chiang^{b,c}^a Department of Physics, Portland State University, P.O. Box 751, Portland, OR 97207-0751, United States^b Institute of Optoelectronic Sciences, National Taiwan Ocean University, Keelung, Taiwan, ROC^c Institute of Physics, Academia Sinica, Taipei, Taiwan, ROC

Received 5 November 2007; received in revised form 21 November 2007; accepted 22 November 2007

In the above communication, we have investigated in details the possibility of observing a large negative lateral Goos–Hanchen (GH) shift from p-polarized light at long wavelength incident onto a bare metal surface, at angles close to grazing incidence. The shift could be up to a few wavelength (e.g. $\sim 20 \mu\text{m}$ at a wavelength of 3390 nm onto silver) and the possible presence of a “pseudo Brewster angle” will not hinder the observability of such an effect. This effect has since been verified experimentally via reflection of IR light from a gold surface [1].

In reviewing the literature, aside from pointing out that our results were in consistency with those hinted at from previous analysis of surface backward waves [2] and of negative energy flow at interface [3], we should have also noted the first explicit calculation by Wild and Giles of such GH shifts at a silver surface which had obtained a (albeit small) negative shift in the order of one wavelength ($\sim 0.5 \mu\text{m}$) [4].

In addition, we would like to emphasize that such large negative GH shift at a metal surface can easily be understood by examining the well-known elementary boundary conditions for the fields across an interface, as applied to the discussion of the continuity of the various components of the Poynting vector in [3].

In fact, if we let the x – z plane be the plane of incidence and apply the following boundary conditions for the normal (N) and tangential (T) field components at the vacuum–metal interface (assuming non-magnetic materials so that $B = H$ and neglecting damping):

$$E_{0N} = \varepsilon E_N, \quad E_{0T} = E_T, \quad H_{0N} = H_N, \quad H_{0T} = H_T \quad (1)$$

we derive immediately, as in [3], the continuity of the energy flow along the interface described by the component of the Poynting vector $S_x \sim (\vec{E} \times \vec{H})_x = E_y H_z$ for s-polarized wave; and by the quantity $\varepsilon S_x \sim -\varepsilon E_z H_y$ for p-polarized wave. Hence we conclude that while there is always a positive GH shift in the s-polarized case, S_x changes by a sign in the p-polarized case when $\varepsilon < 0$ as is the case when the incident frequency is below the plasmon frequency of the metal. This then leads to a negative GH shift [3].

Thus, following the above scheme of thought, one can easily understand how the negative GH shift in metal arises and how such shift can be manifested for p-polarized light, large incidence angle (i.e. close to grazing incidence so that E_z will be large), low incident frequency (so that ε will be more negative), and metal with high plasmon frequency (e.g. aluminum). In addition, one can also extend the above arguments to the case of meta-materials instead of metal where the magnetic permeability can also turn negative [by distinguishing the B field and $H (=B/\mu)$ in (1)]. In this case, it is the continuity of $\mu S_x \sim \mu E_y H_z$ for s-polarized waves, implying that even the s-polarized light will experience negative GH shifts as has been reported in the literature [5]. Along the same line, one can even go further to design interfaces made of different combination of ordinary and meta-materials so that various positive/negative GH shifts may be generated as desired.

We believe the above remarks should help to shed some light on the recently observed negative GH shifts at a bare metal surface [1].

References

- [1] M. Merano, A. Aiello, G.W. 'tHooft, M.P. van Exter, E.R. Eliel, J.P. Woerdman, Opt. Express 15 (2007) 15928.

DOI of original article: [10.1016/j.optcom.2007.04.019](https://doi.org/10.1016/j.optcom.2007.04.019).

* Corresponding author.

E-mail address: hopl@pdx.edu (P.T. Leung).

- [2] A.A. Oliner, T. Tamir, *J. Appl. Phys.* 33 (1962) 231;
T. Tamir, A.A. Oliner, *Proc. IEEE* 51 (1963) 317.
- [3] H.M. Lai et al., *Phys. Rev. E* 62 (2000) 7330.
- [4] W.J. Wild, C.L. Giles, *Phys. Rev. A* 25 (1982) 2099, Note that the result was somewhat overshadowed by that for a semiconductor (germanium) obtained in the same paper (~ 3 times the wavelength), and there was no elaboration for the possibility of observing a much larger negative shift in the metal case, without the possible hindrance by the presence of the “pseudo Brewster angle” as was clarified in our recent work.
- [5] See, e.g., L.G. Wang, S.Y. Zhu, *Appl. Phys. Lett.* 87 (2005) 221102; L.G. Wang, S.Y. Zhu, *J. Appl. Phys.* 98 (2005) 043522.